8-bit parallel-in/serial-out shift register Rev. 3 — 21 September 2021

### 1. General description

The 74LV165-Q100 is an 8-bit serial or parallel-in/serial-out shift register. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and two complementary serial outputs (Q7 and Q7). When the parallel load input (PL) is LOW the data from D0 to D7 is loaded into the shift register asynchronously. When PL is HIGH data enters the register serially at DS. When the clock enable input ( $\overline{CE}$ ) is LOW data is shifted on the LOW-to-HIGH transitions of the CP input. A HIGH on  $\overline{CE}$  will disable the CP input. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess V<sub>CC</sub>.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.0 to 5.5 V
- CMOS low power dissipation
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Complies with JEDEC standards:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - MIL-STD-833, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )

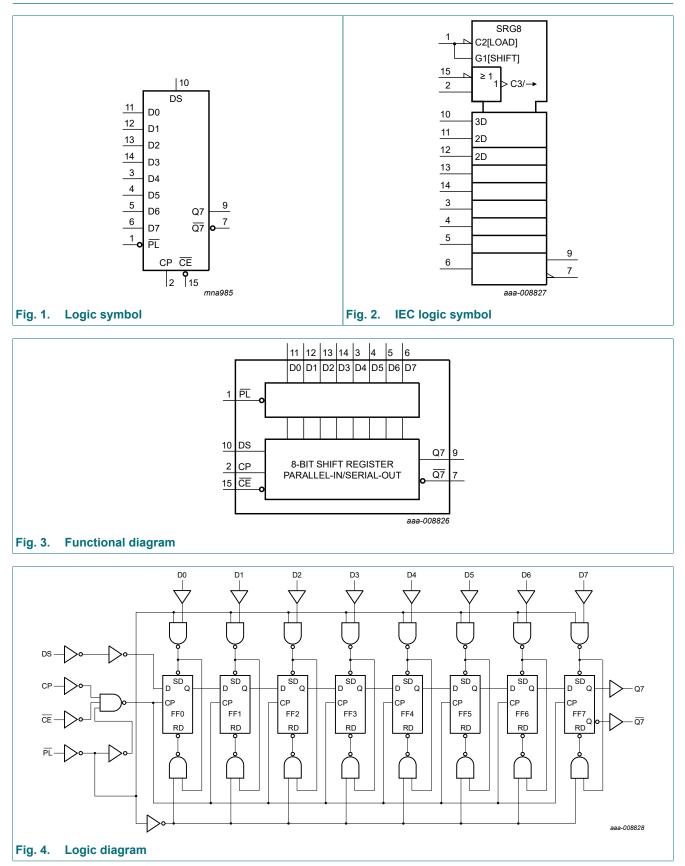
### 3. Ordering information

#### Table 1. Ordering information

Type number	Package							
Temperature range Name Des			Description	Version				
74LV165D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1				
74LV165PW-Q100	-40 °C to +125 °C		plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				

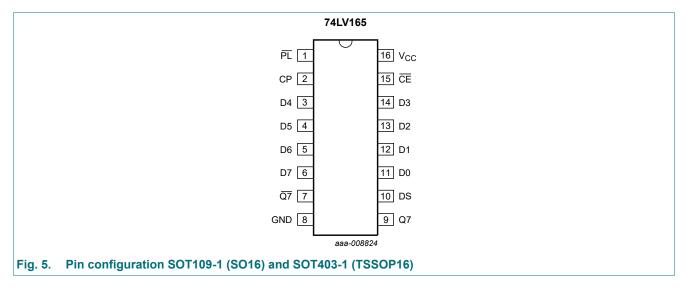
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### 4. Functional diagram



### 5. Pinning information





### 5.2. Pin description

Table 2. Pin description						
Symbol	Pin	Description				
PL	1	parallel enable input (active LOW)				
СР	2	clock input (LOW-to-HIGH edge-triggered)				
Q7	7	complementary serial output from the last stage				
GND	8	ground (0 V)				
Q7	9	serial output from the last stage				
DS	10	serial data input				
D0, D1, D2, D3, D4, D5, D6, D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs				
CE	15	clock enable input (active LOW)				
V <sub>CC</sub>	16	positive supply voltage				

### 6. Functional description

#### Table 3. Function table

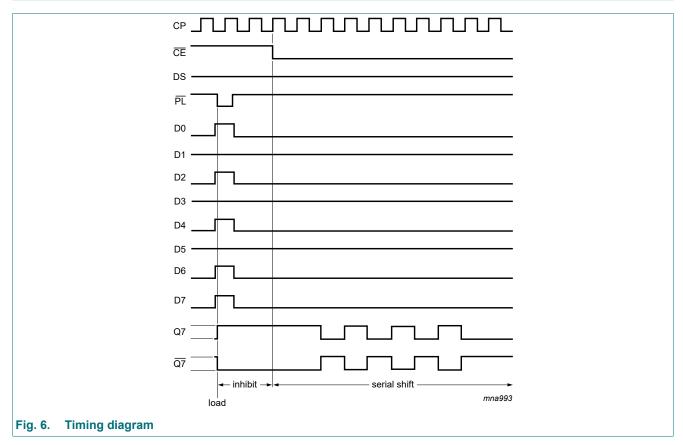
H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

*q* = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$ 

Operating modes	Input	S				Qn reg	isters	Outpu	t
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	<b>Q7</b>
parallel load	L	Х	Х	Х	L	L	L to L	L	Н
	L	Х	Х	Х	Н	Н	H to H	Н	L
serial shift	Н	L	1	I	X	L	q0 to q5	q6	<u>q6</u>
	Н	L	1	h	Х	Н	q0 to q5	q6	<u>q6</u>
hold "do nothing"	Н	Н	Х	Х	X	q0	q1 to q6	q7	q7



### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V) [1]

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 V \text{ or } V_{I} > V_{CC} + 0.5 V$	-	20	mA
VI	input voltage		-0.5	+7	V
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0	-	±50	mA
lo	output current	$-0.5 V < V_{O} < V_{CC} + 0.5 V$	-	±25	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT109-1 (SO16) package: P<sub>tot</sub> derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		1.0	3.3	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.0 V to 2.0 V	0	-	500	ns/V
		V <sub>CC</sub> = 2.0 V to 2.7 V	0	-	200	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	0	-	100	ns/V
		V <sub>CC</sub> = 3.6 V to 5.5 V	0	-	50	ns/V

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### 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-4(	) °C to +8	5 °C	-40 °C to	Unit	
			Min	Typ[1]	Max	Min	Мах	1
VIH	HIGH-level	V <sub>CC</sub> = 1.2 V	0.9	-	-	0.9	-	V
	input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	-	-	1.4	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
	V <sub>CC</sub> = 4.5 V to 5.5 V	0.7V <sub>CC</sub>	-	-	0.7V <sub>CC</sub>	-	V	
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 1.2 V	-	-	0.3	-	0.3	V
	input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.6	-	0.6	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3V <sub>CC</sub>	-	0.3V <sub>CC</sub>	+
V <sub>он</sub>	HIGH-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $I_{O} = -100 \ \mu A$						
	output voltage	V <sub>CC</sub> = 1.2 V	-	1.2		-		+
		V <sub>CC</sub> = 2.0 V	1.8	2.0	-	1.8	-	V
		V <sub>CC</sub> = 2.7 V	2.5	2.7	-	2.5	-	V
		V <sub>CC</sub> = 3.0 V	2.8	3.0	-	2.8	-	V
		V <sub>CC</sub> = 4.5 V	4.3	4.5	-	4.3	-	V
		standard outputs: $V_I = V_{IH}$ or $V_{IL}$						+
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = -6 mA	2.40	2.82	-	2.20	-	V
		V <sub>CC</sub> = 4.5 V; I <sub>O</sub> = -12 mA	3.60	4.20	-	3.50	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; I_{O} = 100 \ \mu\text{A}$						-
	output voltage	V <sub>CC</sub> = 1.2 V	-	0	-	-	-	-
		V <sub>CC</sub> = 2.0 V	-	0	0.2	1.8	0.2	V
		V <sub>CC</sub> = 2.7 V	-	0	0.2	2.5	0.2	V
		V <sub>CC</sub> = 3.0 V	-	0	0.2	2.8	0.2	V
		V <sub>CC</sub> = 4.5 V	-	0	0.2	4.3	0.2	V
		standard outputs: V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 6 mA	-	0.25	0.40	-	0.50	V
		V <sub>CC</sub> = 4.5 V; I <sub>O</sub> = 12 mA	-	0.35	0.55	-	0.65	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	20	-	160	μA
ΔI <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 V;$ $V_{CC} = 2.7 V \text{ to } 3.6 V$	-	-	500	-	850	μA
CI	input capacitance		-	3.5	-	-	-	pF

[1] Typical values are measured at  $T_{amb}$  = 25 °C.

### **10.** Dynamic characteristics

#### Table 7. Dynamic characteristics

GND (ground = 0 V); for test circuit, see Fig. 12

Symbol	Parameter	Conditions	-4	-40 °C to +85 °C			-40 °C to +125 °C	
			Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation delay	CE, CP to Q7, Q7;         [2           see Fig. 7 and Fig. 8						
		V <sub>CC</sub> = 1.2 V	-	115	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	-	38	61	-	76	ns
		V <sub>CC</sub> = 2.7 V	-	27	43	-	54	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3	-	22	36	-	45	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF	-	18	-	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4	-	15	24	-	30	ns
		PL to Q7, Q7; see Fig. 8						
		V <sub>CC</sub> = 1.2 V	-	110	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	-	35	56	-	70	ns
		V <sub>CC</sub> = 2.7 V	-	24	39	-	49	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3	-	20	33	-	41	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF	-	18	-	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4	-	14	22	-	27	ns
		D7 to Q7, Q7; see Fig. 9						
		V <sub>CC</sub> = 1.2 V	-	90	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	-	28	45	-	56	ns
		V <sub>CC</sub> = 2.7 V	-	20	32	-	40	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3	-	17	27	-	33	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF	-	14	-	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4	-	11	18	-	22	ns
t <sub>W</sub>	pulse width	CP input HIGH to LOW; see Fig. 7						
		V <sub>CC</sub> = 2.0 V	34	10	-	41	-	ns
		V <sub>CC</sub> = 2.7 V	25	8	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3	20	7	-	24	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4	15	5	-	18	-	ns
		PL input LOW; see Fig. 8						
		V <sub>CC</sub> = 2.0 V	34	10	-	41	-	ns
		V <sub>CC</sub> = 2.7 V	25	8	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3	20	7	-	24	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4	15	5	-	18	-	ns
t <sub>rec</sub>	recovery time	PL to CP, CE; see Fig. 8						-
		V <sub>CC</sub> = 1.2 V	-	40	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	24	15	-	30	-	ns
		V <sub>CC</sub> = 2.7 V	18	11	-	23	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3	17	10	-	21	-	ns
		$V_{\rm CC} = 4.5 \text{ V to } 5.5 \text{ V}$ [4		7	_	15	_	ns

### 8-bit parallel-in/serial-out shift register

Symbol	Parameter	Conditions	-4	-40 °C to +85 °C			o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
t <sub>su</sub>	set-up time	DS to CP, CE; see Fig. 10						
		V <sub>CC</sub> = 1.2 V	-	-8	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	22	-2	-	26	-	ns
		$V_{CC}$ = 2.7 V	16	-1	-	19	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3	] 13	-1	-	15	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4	] 9	0	-	10	-	ns
		CE to CP, CP to CE; see <u>Fig. 10</u>						
		V <sub>CC</sub> = 1.2 V	-	20	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	22	7	-	26	-	ns
		V <sub>CC</sub> = 2.7 V	16	5	-	19	-	ns
		$V_{\rm CC} = 3.0 \text{ V to } 3.6 \text{ V}$ [3]	] 13	4	-	15	-	ns
		$V_{\rm CC}$ = 4.5 V to 5.5 V [4]	] 9	3	-	10	-	ns
		Dn to PL; see Fig. 11						
		V <sub>CC</sub> = 1.2 V	-	25	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	22	8	-	26	-	ns
		V <sub>CC</sub> = 2.7 V	16	6	-	19	-	ns
		$V_{\rm CC} = 3.0 \text{ V to } 3.6 \text{ V}$ [3]	] 13	5	-	15	-	ns
		$V_{\rm CC}$ = 4.5 V to 5.5 V [4	] 9	4	-	10	-	ns
t <sub>h</sub>	hold time	DS to CP, CE; Dn to PL; see <u>Fig. 10</u> and <u>Fig. 11</u>						
		V <sub>CC</sub> = 1.2 V	-	20	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	22	7	-	26	-	ns
		V <sub>CC</sub> = 2.7 V	16	5	-	19	-	ns
		$V_{\rm CC} = 3.0 \text{ V to } 3.6 \text{ V}$ [3]	] 13	4	-	15	-	ns
		$V_{\rm CC}$ = 4.5 V to 5.5 V [4]	] 9	3	-	10	-	ns
		$\overline{CE}$ to CP, CP to $\overline{CE}$ ; see <u>Fig. 10</u>						
		V <sub>CC</sub> = 1.2 V	-	-30	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	5	-8	-	5	-	ns
		V <sub>CC</sub> = 2.7 V	5	-6	-	5	-	ns
		$V_{\rm CC}$ = 3.0 V to 3.6 V [3]	] 5	-5	-	5	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4	] 5	-4	-	5	-	ns
f <sub>max</sub>	maximum	see <u>Fig. 7</u>						
	frequency	V <sub>CC</sub> = 2.0 V	14	40	-	12	-	MHz
		V <sub>CC</sub> = 2.7 V	19	60	-	16	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V [3	] 24	65	-	20	-	MHz
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF	-	78	-	-	-	MHz
		$V_{\rm CC}$ = 4.5 V to 5.5 V [4]	] 36	75	-	30	-	MHz

#### 8-bit parallel-in/serial-out shift register

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур <mark>[1]</mark>	Мах	Min	Мах	
C <sub>PD</sub>	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC}; $ [5] $V_{CC} = 3.3 \text{ V}$	-	35	-	-	-	pF

[1] Typical values are measured at  $T_{amb}$  = 25 °C.

[2]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[3] Typical values are measured at  $V_{CC}$  = 3.3 V.

[4] Typical values are measured at  $V_{CC}$  = 5.0 V.

[5]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o) (P_D \text{ in } \mu W)$ , where:  $f_i = \text{input frequency in MHz}$ ;

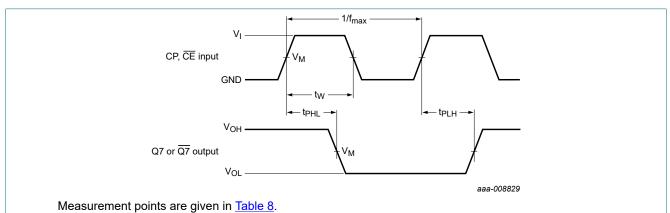
 $f_o$  = output frequency in MHz;

 $\Sigma$  (C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) = sum of outputs;

 $C_L$  = output load capacitance in pF;

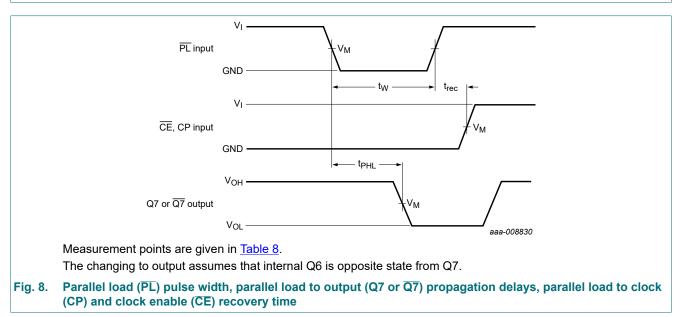
 $V_{CC}$  = supply voltage in V.

### 10.1. Waveforms and test circuit



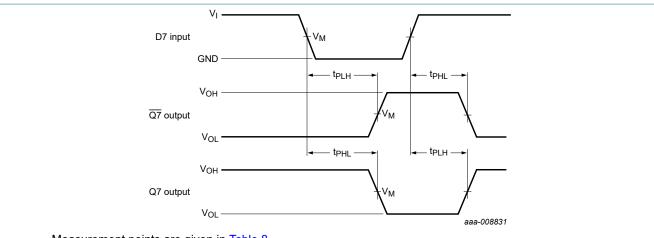
The changing to output assumes that internal Q6 is opposite state from Q7.





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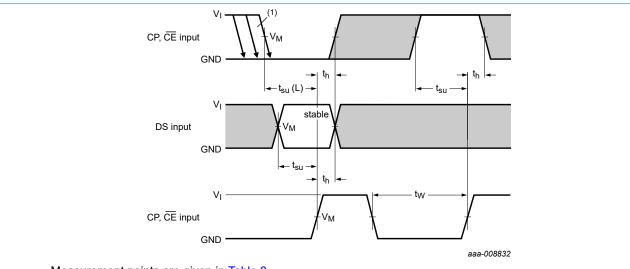
#### 8-bit parallel-in/serial-out shift register



Measurement points are given in <u>Table 8</u>.

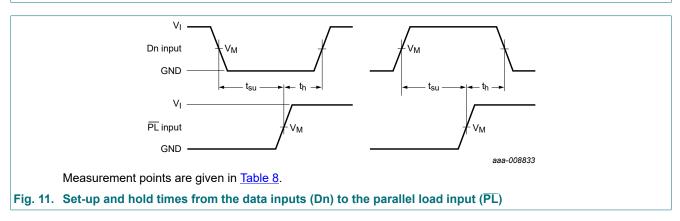
The changing to output assumes that internal Q6 is opposite state from Q7.

#### Fig. 9. Data input (Dn) to output (Q7 or $\overline{Q7}$ ) propagation delays when $\overline{PL}$ is LOW



- Measurement points are given in <u>Table 8</u>.
- (1) CE may change only from HIGH-to-LOW while CP is LOW. The shaded areas indicate when the input is permitted to change for predictable output performance.

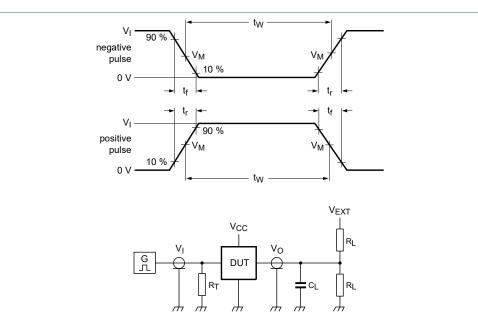




### 8-bit parallel-in/serial-out shift register

	Table 8.	Measurement	points
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Supply voltage	Input	Output
V <sub>cc</sub>	V <sub>M</sub>	V <sub>M</sub>
< 2.7 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
2.7 V to 3.6 V	1.5 V	1.5 V
≥ 4.5 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>



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Test data is given in Table 9.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_{T}$  = Termination resistance should be equal to output impedance  $Z_{o}$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

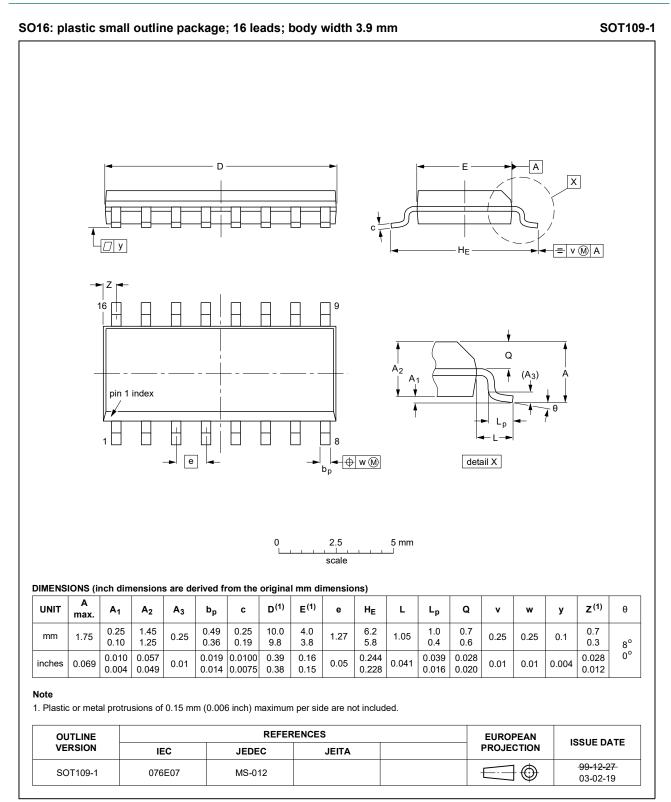
#### Fig. 12. Test circuit for measuring switching times

### Table 9. Test data

Supply voltage	Input		Load	V <sub>EXT</sub>	
	Vi	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>
< 2.7 V	V <sub>CC</sub>	2.5 ns	50 pF	1 kΩ	open
2.7 V to 3.6 V	2.7 V	2.5 ns	50 pF, 15 pF	1 kΩ	open
≥ 4.5 V	V <sub>CC</sub>	2.5 ns	50 pF	1 kΩ	open

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### **11. Package outline**



### Fig. 13. Package outline SOT109-1 (SO16)

74LV165\_Q100

#### 8-bit parallel-in/serial-out shift register

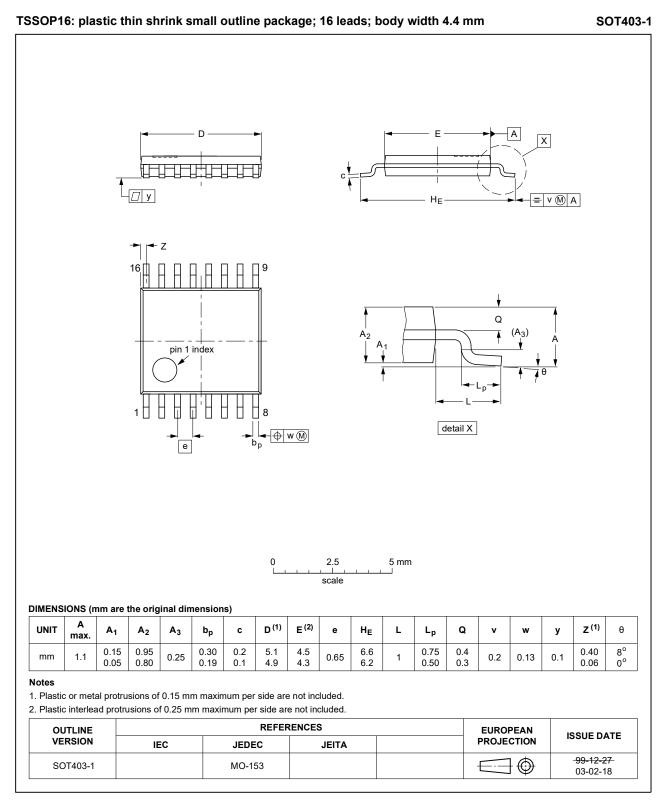


Fig. 14. Package outline SOT403-1 (TSSOP16)

### **12. Abbreviations**

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

### 13. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LV165_Q100 v.3	20210921	Product data sheet	-	74LV165_Q100 v.2	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li><u>Section 1</u> and <u>Section 2</u> updated.</li> <li><u>Section 7</u>: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>				
74LV165_Q100 v.2	20140224	Product data sheet	-	74LV165_Q100 v.1	
Modifications:	Typo corrected	in <u>Table 2</u>			
74LV165_Q100 v.1	20131111	Product data sheet	-	-	

### 14. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### 8-bit parallel-in/serial-out shift register

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